SPDT SWITCH GaAs MMIC

■GENERAL DESCRIPTION

The NJG1543HB3 is a GaAs SPDT switch MMIC which features low loss, high isolation and low control current and ideally suitable for switching the RF receiving circuit of cellular phone.

This switch is operated in the wide frequency range from 100MHz to 3GHz at low voltage from 2.5V.



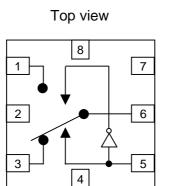


NJG1543HB3

FEATURES

 Low voltage operation Low insertion loss High isolation Low current consumption 	+2.7V typ. 0.6dB typ. @f=2.5GHz, P _{IN} =22dBm 23dB typ. @f=2.5GHz, P _{IN} =22dBm 30uA typ. @2.5GHz, P _{IN} =22dBm
Low control currentPackage	9uA typ. @2.5GHz USB8-B3 (Package size: 1.5x1.5x075mm)

PIN CONFIGURATION



Pin Connection 1.P1 2.GND 3.P2 4.GND 5.VCTL 6.PC 7.VDD 8.GND

TRUTH TABLE

Control Voltage: "H"=V_{CTL (H)}, "L"=V_{CTL (L)}

VCTL	Н	L		
PC-P1	ON	OFF		
PC-P2	OFF	ON		

■ABSOLUTE MAXIMUM RATINGS

 $(T_a=25^{\circ}C, Z_s=Z_l=50\Omega)$

			$(1_{a}=20, 0, 2_{s})$	<u>-2 -0032)</u>
PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNITS
Input Power	P _{IN}	V_{DD} =2.7V, V_{CTL} =0V/2.7V	32	dBm
Supply Voltage	V _{DD}	VDD terminal	7.5	V
Control Voltage	V _{CTL}	VCTL terminal	7.5	V
Power Dissipation	PD	At on PCB board	135	mW
Operating Temp.	T _{opr}		-40~+85	°C
Storage Temp.	T _{stg}		-55~+125	°C

■ELECTRICAL CHARACTERISTICS

(General conditions: $V_{DD}=2.7V$, $V_{CTL (L)}=0V$, $V_{CTL (H)}=2.7V$, $Z_S=Z_I=50\Omega$, $T_a=25^{\circ}C$)						
PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V_{DD}		2.5	2.7	6.5	V
Operating Current	I _{DD}	f=2.5GHz, P _{IN} =22dBm	-	30	50	uA
Control Voltage (LOW)	V _{CTL (L)}		0.0	-	0.8	V
Control Voltage (HIGH)	V _{CTL (H)}		2.0	-	V_{DD}	V
Control Current	I _{CTL}	f=2.5GHz, P _{IN} =22dBm	-	9	18	uA
Insertion Loss	Loss	f=2.5GHz, P _{IN} =22dBm	-	0.6	0.8	dB
Isolation	ISL	f=2.5GHz, P _{IN} =22dBm	21	23	-	dB
Pout at 0.2dB compression point	$P_{-0.2dB}$	f=2.5GHz	23	27	-	dBm
VSWR	VSWR	f=0.1~2.5GHz, ON state	-	1.1	1.3	
Switching Time	T _{SW}	f=0.1~2.5GHz	-	1	-	us

■ELECTRICAL CHARACTERISTICS

(General conditions: V_{DD}=2.7V, V_{CTL (L)}=0V, V_{CTL (H)}=2.7V, Z_S=Z_I=50Ω, T_a=-40~+75°C)

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PARAMETERS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Supply Voltage	V _{DD}		2.5	2.7	6.5	V
Operating Current	I _{DD}	f=2.5GHz, P _{IN} =22dBm	-	30	70	uA
Control Voltage (LOW)	V _{CTL (L)}		0.0	-	0.8	V
Control Voltage (HIGH)	V _{CTL (H)}		2.0	-	V_{DD}	V
Control Current	I _{CTL}	f=2.5GHz, P _{IN} =22dBm	-	-	25	uA
Insertion Loss	Loss	f=2.5GHz, P _{IN} =22dBm	-	-	1.5	dB
Isolation	ISL	f=2.5GHz, P _{IN} =22dBm	18	-	-	dB
Pout at 0.2dB compression point	P _{-0.2dB}	f=2.5GHz	17	-	-	dBm
VSWR	VSWR	f=0.1~2.5GHz, ON state	-	-	1.3	
Switching Time	T _{sw}	f=0.1~2.5GHz	-	-	3	us

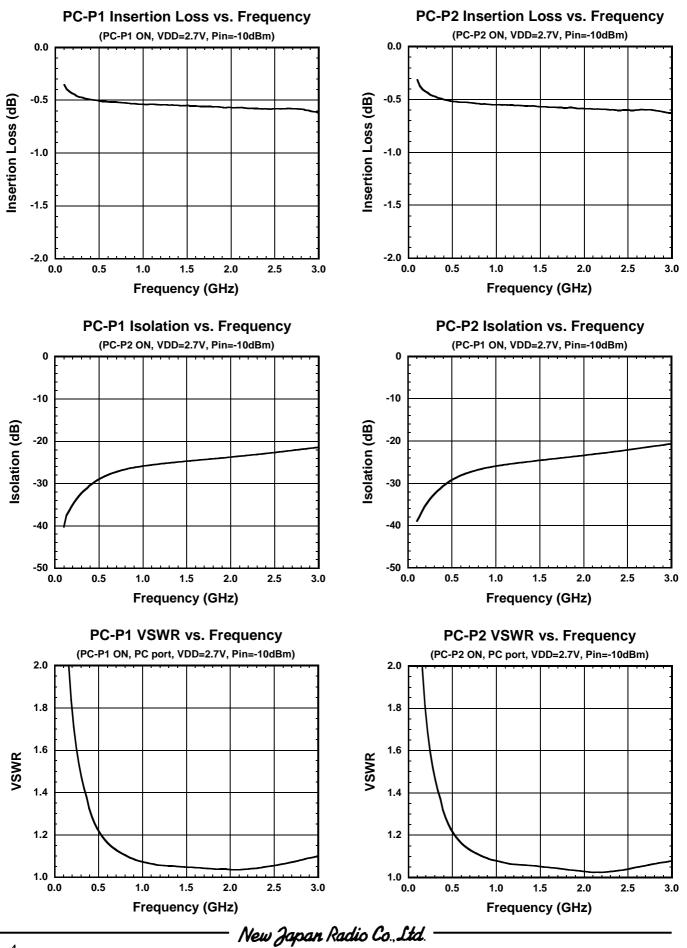
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TERMINAL INFORMATION

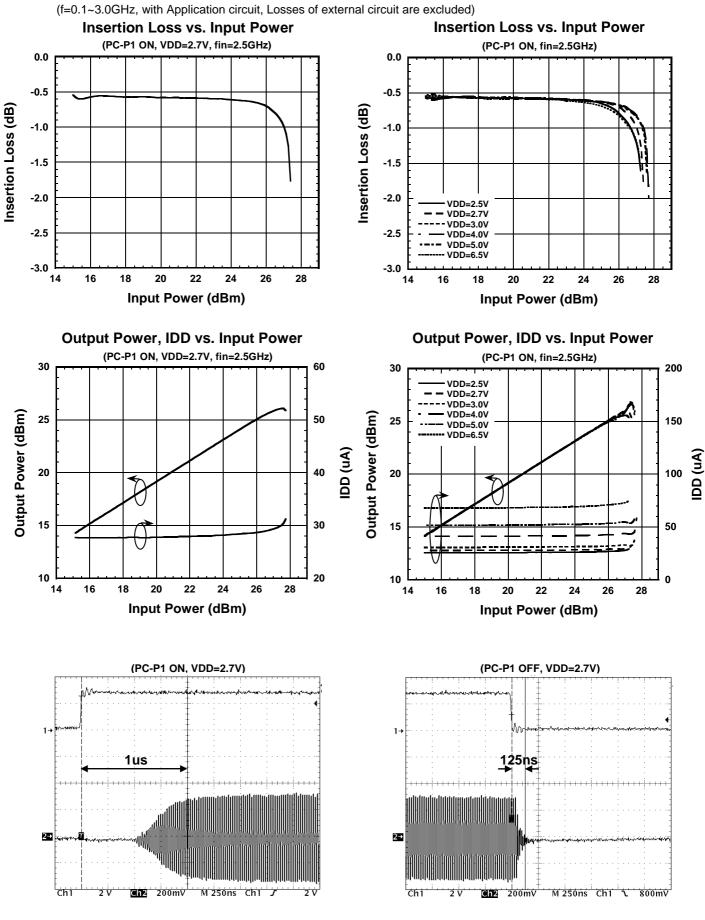
Pin	Symbol	Description
1	P1	RF port. This port is connected with PC port by controlling 5 pin (VCTL) to $2.0V \sim V_{DD}$. An external capacitor is required to block the DC bias voltage of internal circuit.
2	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
3	P2	RF port. This port is connected with PC port by controlling 5 pin (VCTL) to 0V~+0.8V. An external capacitor is required to block the DC bias voltage of internal circuit.
4	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.
5	VCTL	Control port. This terminal is set to High-Level by 2V~V _{DD} , and Low-Level by +0.8~0V.
6	PC	Common RF port. In order to block the DC bias voltage of internal circuit, an external capacitor is required.
7	VDD	Positive voltage supply terminal. The positive voltage (+2.5~+6.5V) have to be supplied. The bypass capacitor should be connected with GND as close as possible for excellent RF performance.
8	GND	Ground terminal. Please connect this terminal with ground plane as close as possible for excellent RF performance.

ELECTRICAL CHARACTERISTICS

(f=0.1~3.0GHz, with Application circuit, Losses of external circuit are excluded)



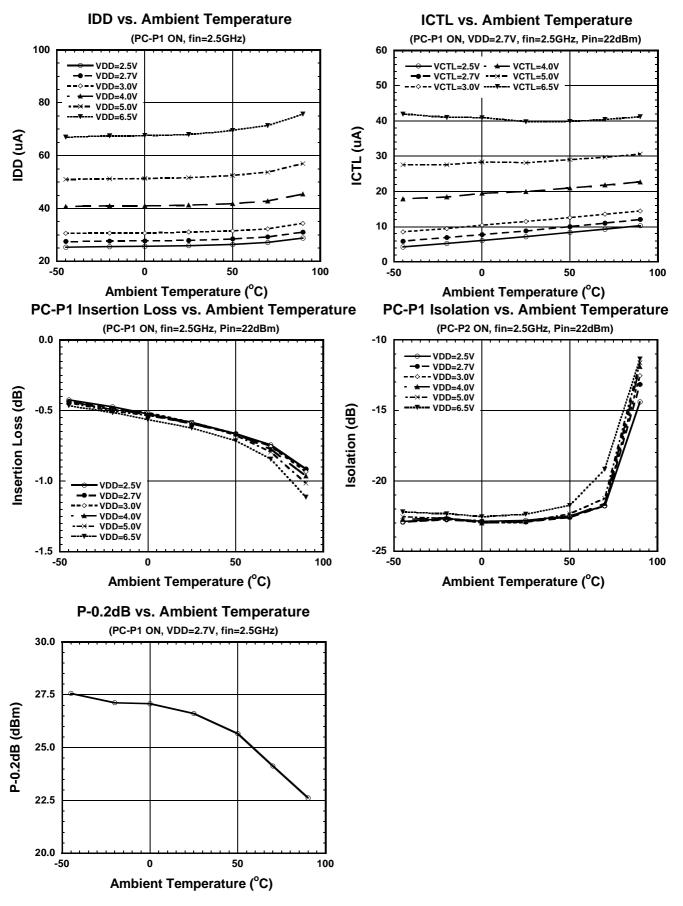
■ELECTRICAL CHARACTERISTICS



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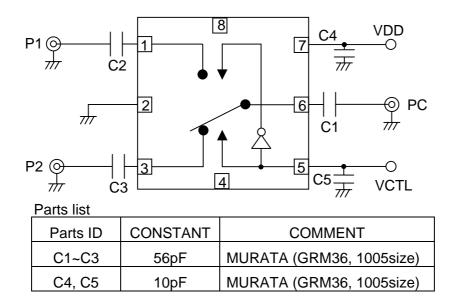
ELECTRICAL CHARACTERISTICS

(f=0.1~3.0GHz, with Application circuit, Losses of external circuit are excluded)

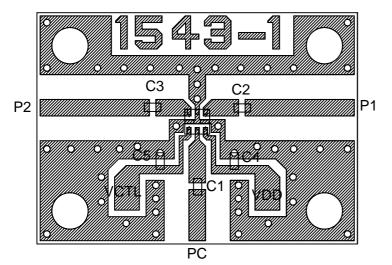


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■APPLICATION CIRCUIT



■RECOMMENDED PCB DESIGN



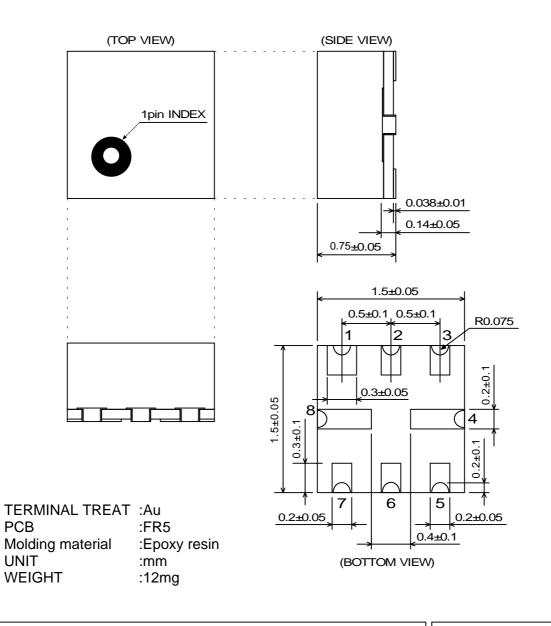
PCB:FR-4, t=0.5mm Capacitor: Size 1005 Strip Line Width=1.0mm PCB Size: 19.4x14.0mm Circuit losses including losses of capacitors and connectors

freq (GHz)	Loss (dB)		
0.8	0.11		
1.0	0.12		
1.5	0.16		
1.8	0.19		
2.0	0.21		
2.5	0.27		

PRECAUTIONS

- [1] The DC blocking capacitor have to be placed at RF terminal of PC1, PC2, PC.
- [2] To reduce stripline influence on RF characteristics, please locate bypass capacitors (C4, C5) close to each terminal.
- [3] To avoid degradation of isolation or high power characteristics, please layout ground pattern right under this IC.

■PACKAGE OUTLINE (USB8-B3)



Cautions on using this product

- This product contains Gallium-Arsenide (GaAs) which is a harmful material.
- Do NOT eat or put into mouth.
- Do NOT dispose in fire or break up this product.
- Do NOT chemically make gas or powder with this product.
- To waste this product, please obey the relating law of your country.

[CAUTION]

[CAUTION] The specifications on this databook are only given for information , without any guarantee as regards either mistakes or omissions. The application circuits in this databook are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

This product may be damaged with electric static discharge (ESD) or spike voltage. Please handle

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